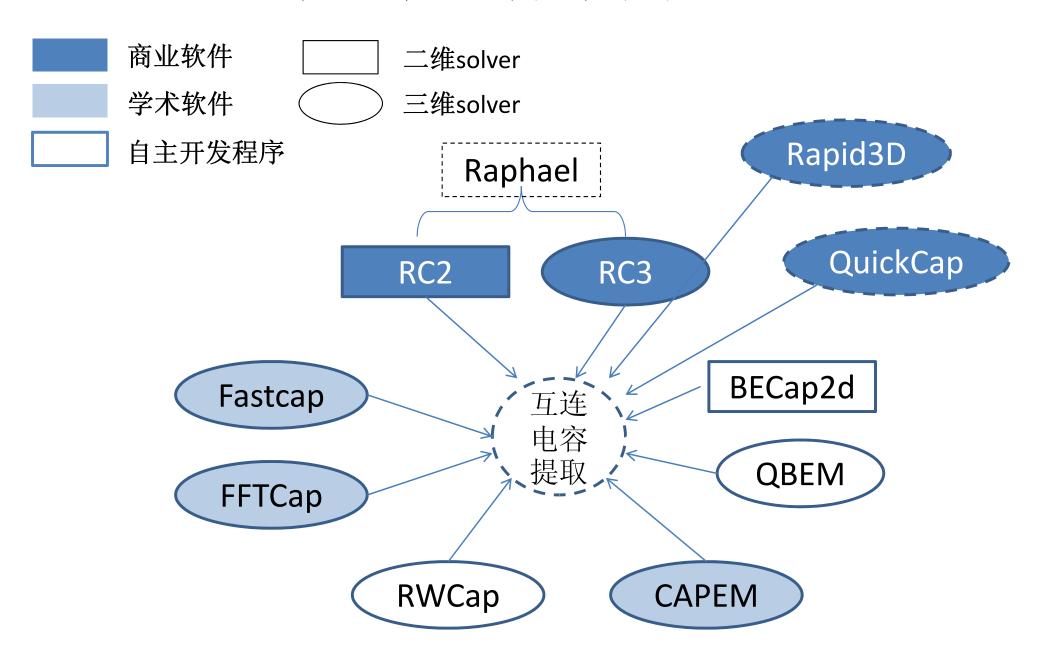
## Capacitance Field Solvers

喻文健

## 几种电容求解器





# Capacitance extraction

- 3-D numerical methods general approach
  - $\square$  Set voltages on conductor; solve for  $Q_i$

$$Q_i = \sum_{j=1}^{N} C_{ij} U_j$$
,  $i=1, 2, ..., N$ 

 $Q_i = \sum_{j=1}^N C_{ij} U_j \ , \qquad i=1,2,...,N,$  Solve the electrostatic field for  $\emph{u}$ , then  $\ Q_i = \int_{\Gamma_i} \varepsilon \cdot \frac{\partial \emph{u}}{\partial \emph{n}}$ 

- ☐ Global method to get the whole matrix
- Classification
  - □ Volume discretization: FDM, FEM

Raphael's RC3 – Synopsys

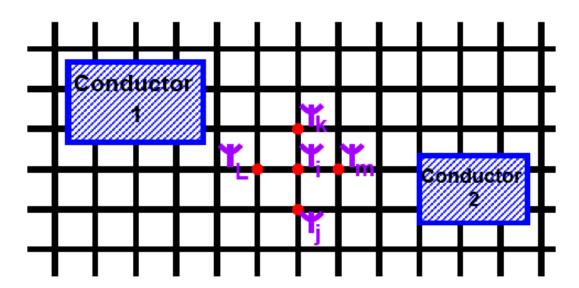
□ Boundary integral (element) method <sup>Q3D</sup> — <sup>Ansoft</sup>

FastCap, QBEM, HiCap

Stochastic method

□ Others – semi-analytical approaches QuickCap - Magma

#### Volume Methods - Finite-Differences/Finite-Elements



Solve Laplace's equation,  $\nabla \cdot \epsilon \nabla \Psi = 0$  in the conductor exterior.

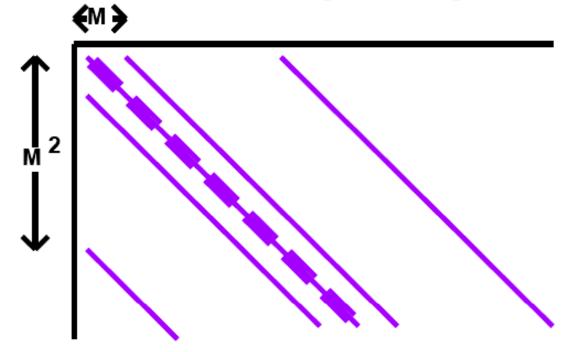
- Approximate derivatives by finite-differences.
- Conductors provide potential boundary conditions (e.g., 1 on conductor 1, zero on conductor 2).
- 2-D example

$$\frac{\partial^{2}\Psi}{\partial x^{2}} + \frac{\partial^{2}\Psi}{\partial y^{2}} \approx \frac{\frac{\Psi_{m} - \Psi_{i}}{x_{m} - x_{i}} - \frac{\Psi_{i} - \Psi_{L}}{x_{i} - x_{L}}}{0.5\left((x_{m} - x_{i}) + (x_{i} - x_{L})\right)} + \frac{\frac{\Psi_{k} - \Psi_{i}}{y_{l} - y_{i}} - \frac{\Psi_{i} - \Psi_{j}}{y_{i} - y_{j}}}{0.5\left((y_{l} - y_{i}) + (y_{i} - y_{L})\right)}$$

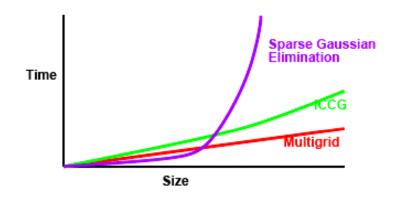
#### Volume Methods generate sparse matrices



- One equation for each grid node
- In 3-D, each equation involves at least 7 variables
  - Up-Down for  $\frac{\partial}{\partial z}$ , Left-Right for  $\frac{\partial}{\partial x}$ , Backward-Forward for  $\frac{\partial}{\partial y}$
- $\bullet$  Sparse matrix for an  $M \times M \times M$  grid is Large



#### Matrix Solution Methods.

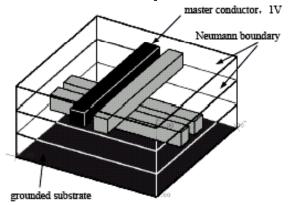


- Sparse Gaussian Elimination
  - Direct, complicated data structures, existing packages.
  - Order  $N^2$  time and storage.
- Incomplete Cholesky Conjugate-Gradient Method (ICCG)
  - Iterative, easy to program, fast when ground planes nearby.
  - Order NlogN time and Order N storage.
- Multigrid methods
  - Iterative, complicated for general grids, fast convergence.
  - Order N time and storage.



# Capacitance extraction

- Volume methods
  - What's the size of simulation domain?
  - □ Two kinds of problem: finite domain and infinite domain



 $\begin{array}{c|c} +C_{1\infty} & -C_{1\infty} \\ +C_{12} & \\ \hline \end{array}$ 

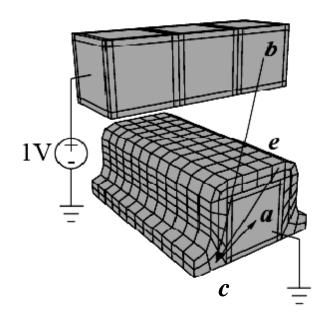
□ Which one is correct?

- both in most time
- 3-D extraction is not performed directly on a "real" case
- In the chopping & combination procedure, both models used
- Because of attenuation of electric field, the results from two models can approach to each other

Because of its nature, volume methods use finite-domain model

#### Integral Formulation Example

#### inside alg. of FastCap



• Influence of charge on panel c at the center of panel a is

$$\frac{q_c}{A_c} \int_{\text{panel } c} \frac{1}{r_{ac}} dA.$$

• Potential at panel a is sum of all contributions:

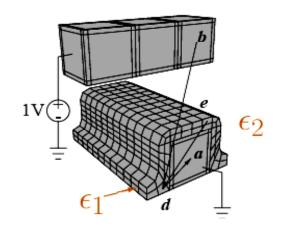
$$v_a = \cdots + q_c \left( \frac{1}{A_c} \int_{\text{panel } c} \frac{1}{r_{ac}} dA \right) + \cdots + q_b \left( \frac{1}{A_b} \int_{\text{panel } b} \frac{1}{r_{ab}} dA \right) + \cdots$$

MoM (method of moment)

Method of virtual charge

Indirect boundary element method

#### Include the Effects of the Dielectric Interfaces



• Dielectric panel d's charge contributes to  $v_a$ , as did b and c.

Polarized charge

• To force  $0 = \epsilon_1 E_{n1} - \epsilon_2 E_{n2}$  at panel d's center:

$$0 = \dots + q_e \left[ (\epsilon_1 - \epsilon_2) \frac{\partial}{\partial \hat{n}} \frac{1}{A_e} \int_{\text{panel } e} \frac{1}{r_{de}} dA \right]$$
  
 
$$+ \dots + q_b \left[ (\epsilon_1 - \epsilon_2) \frac{\partial}{\partial \hat{n}} \frac{1}{A_b} \int_{\text{panel } b} \frac{1}{r_{db}} dA \right] + \dots.$$

#### Pack into Matrices

$$\begin{bmatrix} v_1 \\ \vdots \\ v_{n_p} \\ 0 \\ \vdots \\ 0 \end{bmatrix} = \begin{bmatrix} P_{11} & P_{12} & \cdots & P_{1n} \\ \vdots & \vdots & & \vdots \\ P_{n_p1} & P_{n_p2} & \cdots & P_{n_pn} \\ E_{n_p+1, 1} & E_{n_p+1, 2} & \cdots & E_{n_p+1, n} \\ \vdots & \vdots & & \vdots \\ E_{n1} & E_{n2} & \cdots & E_{nn} \end{bmatrix} \begin{bmatrix} q_1 \\ \vdots \\ q_{n_p} \\ q_{n_p+1} \\ \vdots \\ q_n \end{bmatrix}$$

$$P_{ij} \stackrel{\triangle}{=} \frac{1}{A_j} \int_{\text{panel } j} \frac{1}{r_{ij}} dA;$$

$$E_{ij} \stackrel{\triangle}{=} \frac{\partial}{\partial \hat{n}} \frac{1}{A_j} \int_{\text{panel } j} \frac{1}{r_{ij}} dA, \quad i \neq j.$$

Solve 
$$A\vec{x} = \vec{b}$$
 System

where 
$$A = \begin{bmatrix} P \\ E \end{bmatrix}$$
 is a  $(\# \text{ of panels}) \times (\# \text{ of panels})$  dense matrix.

- Direct methods like Gaussian Elimination require  $n^3$  operations.
- Iterative methods such as GMRES requires  $n^2$  operations.
- Both direct and iterative methods require  $n^2$  storage.

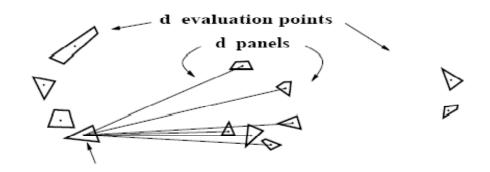
#### Solve $A\vec{x} = \vec{b}$ Iteratively

- 1. Guess charges,  $\tilde{\vec{x}}$ .
- 2. Calculate  $A\tilde{\vec{x}}$ —costs  $O(n^2)$ .
- 3. If  $A\tilde{\vec{x}}$  does not equal b, fix  $\tilde{\vec{x}}$ .

#### Speed Up $A\vec{x}$ Product

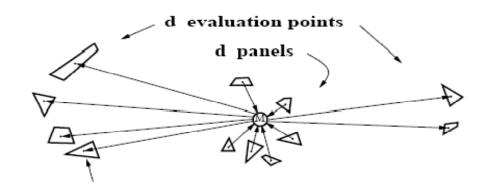
- Computing  $A\vec{x}$  is equivalent to computing n potentials and electric fields from n charges.
- Accelerate matrix-vector products using potential approximations.
- Save Memory by not forming A

#### Direct Potential Evaluation



• Computing d potentials due to d panels costs  $d^2$  operations.

#### Multipole Potential Evaluation



 Multipole Approximations compute d potentials due to d panels is order d operations.

Multipole expansion with order l

$$l=0: \qquad \frac{\sum\limits_{i=1}^{n_2} q_i}{r_j},$$



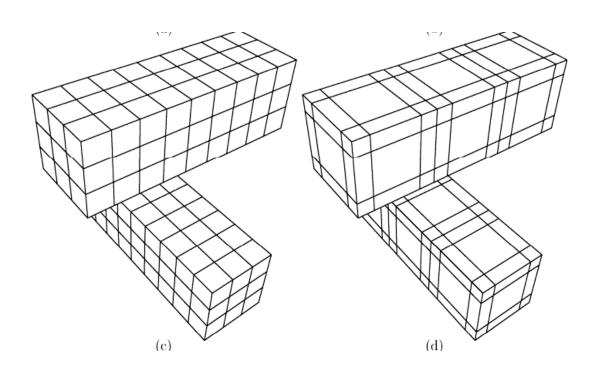
#### ■功能

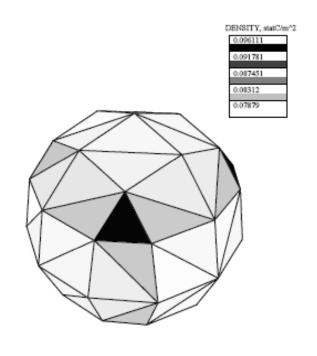
□输入格式: 形体描述、边界划分描述

□ 计算功能: 指定主导体、整个矩阵

□ 附加功能: 形体可视化、计算结果可视化

开放源码!





## М

### FastCap简介

- ■输入格式
  - □两种表面:导体-介质交界面,介质-介质交界面
  - □需要指定所有表面的离散化情况(panel)
  - ☐ Fastcap generic file format, PATRAN neutral file

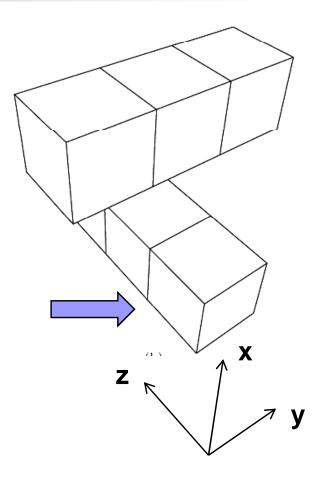
#### Generic file format

- □.qui文件,文本格式,描述每个panel的顶点坐标
- □ 第一行为标题行,以"0"开始; "\*"开始行为注释
- □每行描述一个panel, 两种开始字符: T (三角形), Q (四边形)
- - □导体名字常用数字表示,点必须按顺时针或逆时针顺序



#### Generic file format

```
0.0 0.0 0.0 1.0 0.0 0.0
                  1.0 1.0 0.0 0.0 1.0 0.0
0.0 0.0 0.0 1.0 0.0 0.0 1.0 0.0 1.0
                            0.0 0.0 1.0
0.0 0.0 1.0 1.0 0.0 1.0 1.0 0.0 2.0 0.0 0.0 2.0
0.0 0.0 2.0 1.0 0.0 2.0 1.0 0.0 3.0 0.0 0.0 3.0
0.0 1.0 1.0 1.0 1.0 1.0 1.0 1.0 2.0 0.0 1.0 2.0
0.0 1.0 2.0 1.0 1.0 2.0 1.0 1.0 3.0 0.0 1.0 3.0
1.0 1.0 1.0 1.0 0.0 1.0 1.0 0.0 2.0 1.0 1.0 2.0
1.0 1.0 2.0 1.0 0.0 2.0 1.0 0.0 3.0 1.0 1.0 3.0
0.0 1.0 1.0 0.0 0.0 1.0 0.0 0.0 2.0 0.0 1.0 2.0
0.0 1.0 2.0 0.0 0.0 2.0 0.0 0.0 3.0 0.0 1.0 3.0
0.0 0.0 3.0 1.0 0.0 3.0 1.0 1.0 3.0 0.0 1.0 3.0
    (把导体"1"重命名为Big)
```



- ■描述复杂形体的List文件
  - □用List (.lst)文件将多个.qui文件组合起来
  - □可描述多介质结构和复杂形体

# M

## FastCap简介

- ■描述复杂形体的List文件
- G <group name> (给后续"+"连接的group重命名)
- C <file> <outperm> <xtran> <ytran> <ztran> [+]
- D <file> <outperm> <inperm> <xtran> <ytran> <ztran> <xref> <yref> <zref> [-]
- B <file> <outperm> <inperm> <xtran> <ytran> <ztran> <xref> <yref> <zref> [-][+]
  - □ C: 导体-介质交界面,一般的导体表面
  - □ D: 介质-介质交界面
  - □ B: 无限薄的导体板,这个面兼具C, D的特点
  - □ x/y/ztran: 将.qui文件中所有坐标偏移这个量
  - □ Out/inperm: 介质的介电常数
  - □ x/y/zref: 指定一个参考点坐标,该点在outperm的介质那边, 若写了"-"则该点在inperm的介质那边
  - □+使不同行文件中同名导体成为一个导体, 同属一group



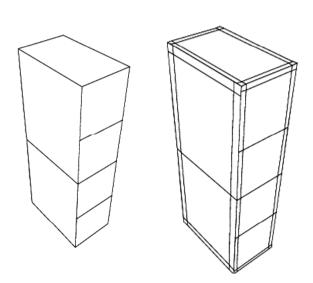
■描述复杂形体的List文件

```
* 1x1 bus crossing problem with dielectric on lower conductors
*
* conductor to air interfaces
C cond_air_1x1.qui 1.0 0.0 0.0 0.0 +
*
* conductor to dielectric interfaces
C cond_dielec_1x1.qui 7.5 0.0 0.0 0.0
```

- □ cond\_air\_1x1.qui和cond\_dielec\_1x1.qui中都包含名 字为1的导体
- □ "+"使这两个导体合成1个,全局名字为1%GROUP1
- □ 若没有"+",它们属于不同组,名字为1%GROUP1, 1%GROUP2



- Generic file generator程序
  - □ Busgen: 平行总线结构(多根平行线); Cubegen: 立方体导体; Capgen: 平板电容器(两块导体板)
  - □ 生成.qui文件到标准输出
  - □ \$ cubegen -n1 -xh1 -yh1 -zh3 > cube113.qui (pp. 16)
  - □-n:每个矩形面最短边分的份数,-x/y/zh三个方向长度
  - □ \$ cubegen -n1 -xh1.5 -yh2.5 -zh6
  - □ \$ cubegen -n3 -xh1.5 -yh2.5 -zh6
  - □ -e: edge to inner panel width ratio 缺省值为0.1
  - □详细命令参数设定,见[1][2]



## M

## FastCap简介

- 构造FastCap输入的一般方法
  - □小规模例子:用Generator程序生成.qui文件,手写.lst 文件组合多个.qui文件
  - □ 较大规模例子:编程写.qui文件(单介质问题);编程写.lst文件(多介质、或复杂问题)

#### ■ FastCap使用命令

```
fastcap [-o<expansion order>] [-d<partitioning depth>] [<input file>]
        [-p<permittivity factor>] [-rs<cond list>] [-ri<cond list>]
        [-] [-l<list file>] [-t<iter tol>]
```

- □-o,-d,-t: 影响多极展开、方程求解计算效率,不用设置
- □-p: 介电常数加倍比例
- □-rs: 求解过程中去掉主导体,否则每个都做一次主导体
- □-ri: 从输入文件中去掉导体,可方便求解一个子结构

# М

## FastCap简介

[yuwj@linux90 bin]\$ fastcap cube1.qui (cubegen -n1 -xh1.5 -yh2.5 -zh6) Running fastcap 2.0 (18Sep92) Number of conductor panels: 14 Input: cube1.qui Number of dielectric interface panels: 0 Input surfaces: Number of thin conductor on dielectric **GROUP1** interface panels: 0 cube1.qui, conductor Number of conductors: 1 title: `1.5mX2.5mX6m cube (n=1 e=0.1)' No expansions at level 3 (lowest) outer permittivity: 1 No expansions at level 2 number of panels: 14 Percentage of multiplies done by number of extra evaluation points: 0 multipole: 0% translation: (0 0 0) Warning: no multipole acceleration Date: Tue Jan 18 12:09:15 2011 Host: linux90 ITERATION DATA Starting on column 1 (1%GROUP1) INPUT SUMMARY 1234 Expansion order: 2 CAPACITANCE MATRIX, nanofarads Number of partitioning levels: 3 Overall permittivity factor: 1 Total number of panels: 14 1%GROUP1 1 0.2185



#### ■ FastCap使用命令

- □除了8个基本参数,后面的都用于图形可视化
- □最重要的是-m参数,生成形体和划分的.ps文件
- □-q: 显示电荷密度分布图, 针对每种主导体设置, 生成一个.ps文件



- ■参考资料
  - □ 获取源代码: Google "Fastcap MIT"
  - □在Linux环境下编译、安装
  - □ 随软件包发布的文档资料:
  - ☐ "FastCap USER'S GUIDE"
  - □ "A nice supplementary user's g

